ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

Title of Invention

PFET-BASED ESD PROTECTION STRATEGY FOR IMPROVED EXTERNAL LATCH-UP ROBUSTNESS

Application Number :

Confirmation Number:

First Named Applicant:

Kiran Chatty

Attorney Docket Number:

BUR920030045US1

Art Unit: Examiner:

Search string:

(5140401 or 5208719 or 5287241 or 5304839 or 5440162 or 5477413 or 5479039 or 5637900 or 5644459 or 5719733 or 5745323 or 5783850 or 5869873 or 5872378 or 5907464 or 5939753 or 5946175 or 5991134 or 5998247 or 6033949 or 6040603 or 6046087 or 6157065 or 6181214 or 6215156 or 6232206 or 6256184 or 6309940 or 6337787 or 6411480 or 6417541 or 6476449 or 6563176 or 6566715 or 6566717 or 6566911 or 20010010954 or 20020105766 or 20020115250 or 20020118499 or

20020153564 or 20020154463 or 20020195663 or 20020195665).pn

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Note: Applicant is not required to submit a paper copy of cited US Patent Documents

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S	TATEMENT E	3Y /	APPLICANT	First Named Inventor	Kiran V. CHATTY		
l				Art Unit	To Be Assigned		
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